NSN 5961-01-337-6449

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-337-6449 **Inclosure Material:** Glass or ceramic or metal **Overall Length:** 4.8 millimeters **Terminal Length:** 28.0 millimeters **Overall Diameter:** 2.6 millimeters **End Application:** Tactical air operations module **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes collector current, dc **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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